



## UT2301

Power MOSFET

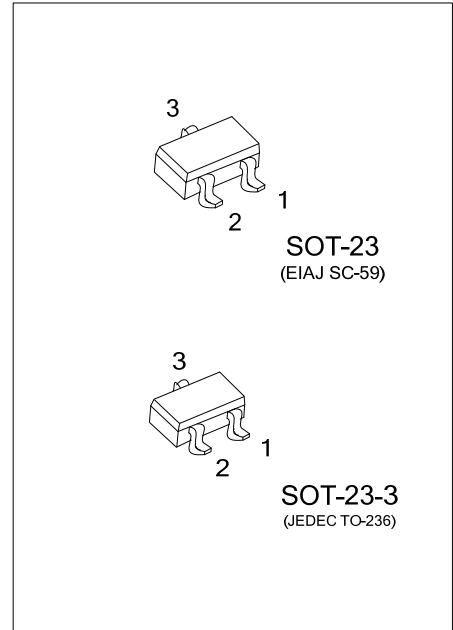
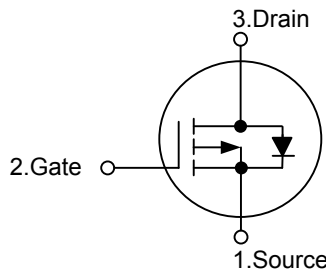
### Y2.8A, 20V P-CHANNEL ENHANCEMENT MODE POWER MOSFET

#### DESCRIPTION

The UTC **UT2301** is P-channel enhancement mode power MOSFET, designed in serried ranks. With fast switching speed, low on-resistance, favorable stabilization.

Used in commercial and industrial surface mount applications and suited for low voltage applications such as DC/DC converters.

#### SYMBOL



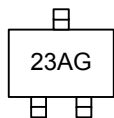
#### ORDERING INFORMATION

| Ordering Number | Package  | Pin Assignment |   |   | Packing   |
|-----------------|----------|----------------|---|---|-----------|
|                 |          | 1              | 2 | 3 |           |
| UT2301G-AE2-R   | SOT-23-3 | S              | G | D | Tape Reel |
| UT2301G-AE3-R   | SOT-23   | S              | G | D | Tape Reel |

Note: Pin Assignment: G: Gate D: Drain S: Source

|  |  |
|--|--|
|  | <p>(1) R: Tape Reel</p> <p>(2) AE2: SOT-23-3, AE3: SOT-23</p> <p>(3) G: Halogen Free and Lead Free</p> |
|--|--|

#### MARKING



■ ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ , unless otherwise specified)

| PARAMETER                        | SYMBOL    | RATING     | UNIT             |
|----------------------------------|-----------|------------|------------------|
| Drain-Source Voltage             | $V_{DSS}$ | -20        | V                |
| Gate-Source Voltage              | $V_{GSS}$ | $\pm 8$    | V                |
| Continuous Drain Current         | $I_D$     | -2.8       | A                |
| Pulsed Drain Current (Note 1, 2) | $I_{DM}$  | -10        | A                |
| Total Power Dissipation          | $P_D$     | 1.14       | W                |
| Junction Temperature             | $T_J$     | +150       | $^\circ\text{C}$ |
| Storage Temperature              | $T_{STG}$ | -55 ~ +150 | $^\circ\text{C}$ |

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

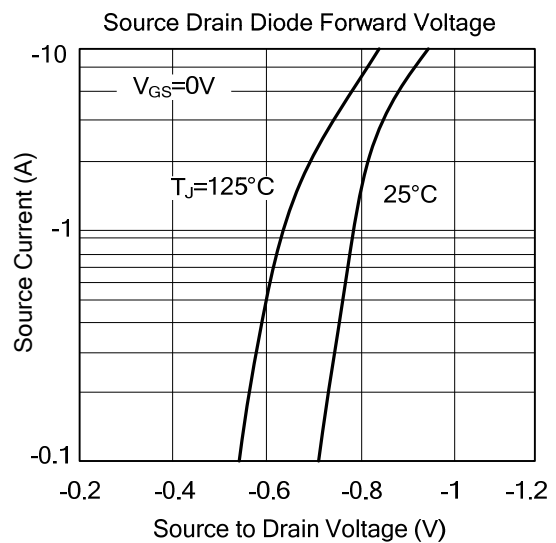
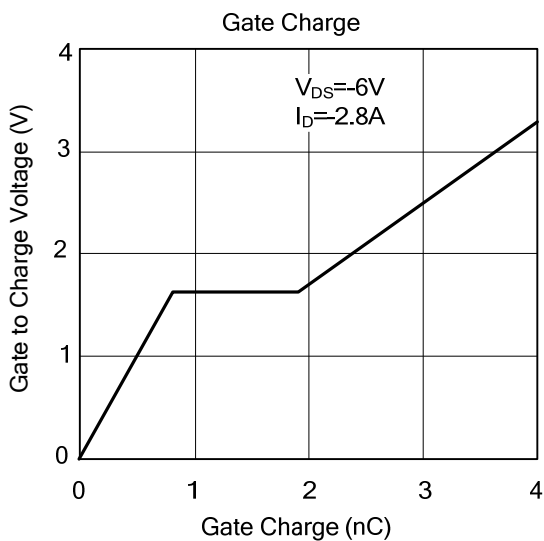
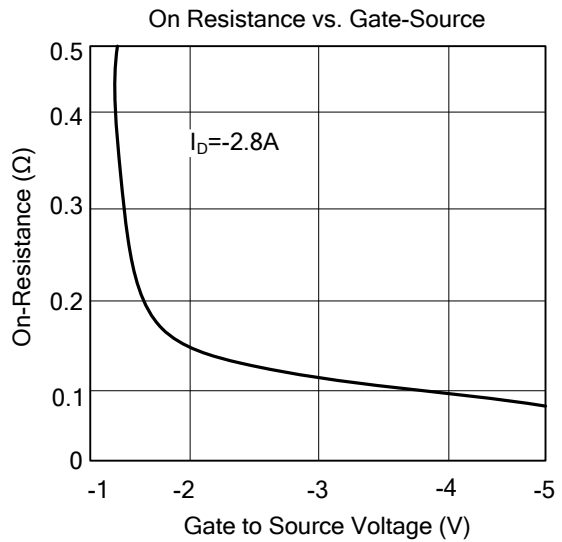
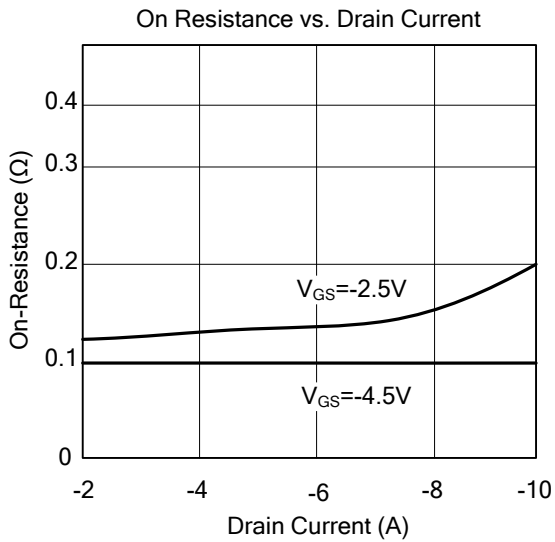
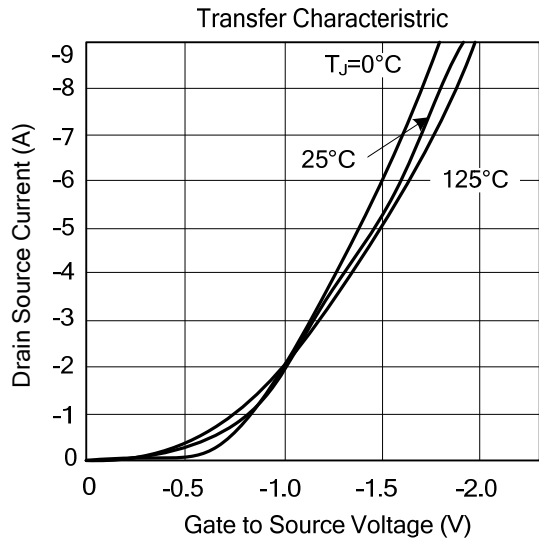
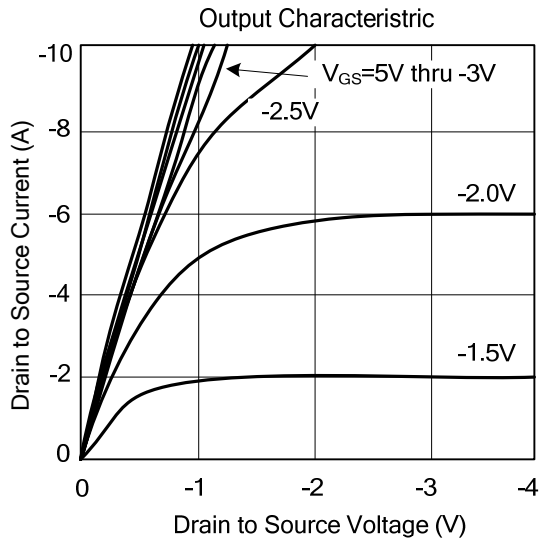
| PARAMETER                    | SYMBOL        | RATING | UNIT               |
|------------------------------|---------------|--------|--------------------|
| Junction to Ambient (Note 3) | $\theta_{JA}$ | 110    | $^\circ\text{C/W}$ |

■ ELECTRICAL CHARACTERISTICS ( $T_J=25^\circ\text{C}$ , unless otherwise specified)

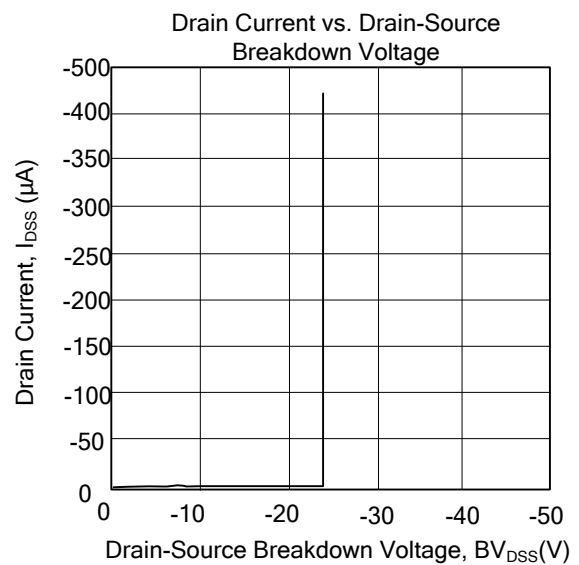
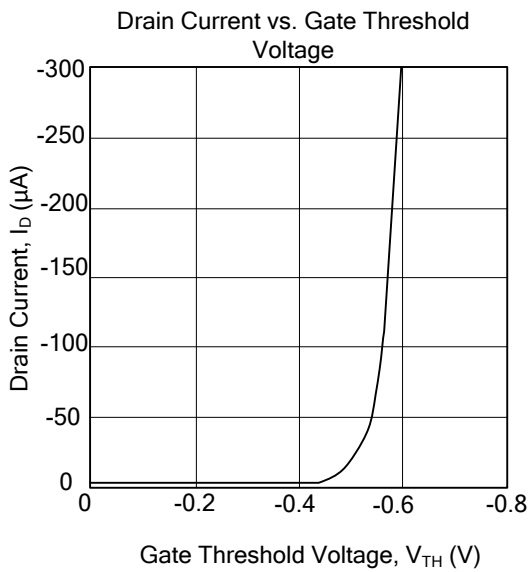
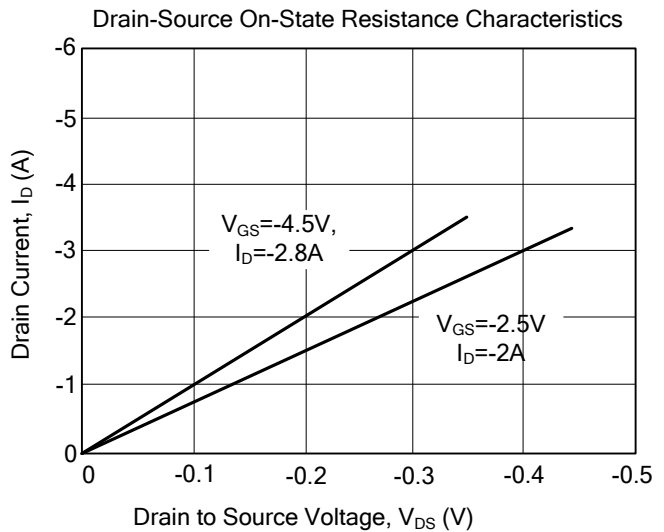
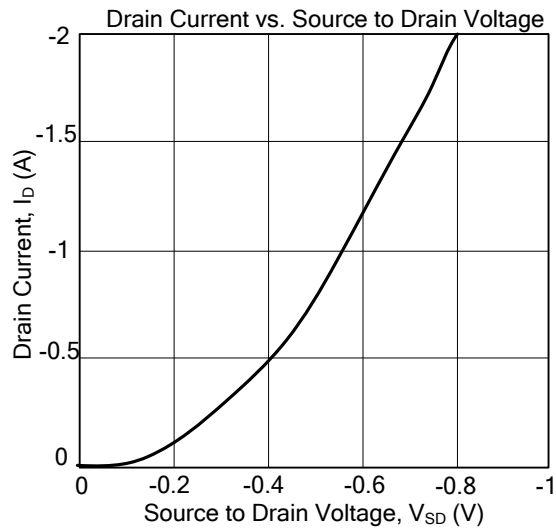
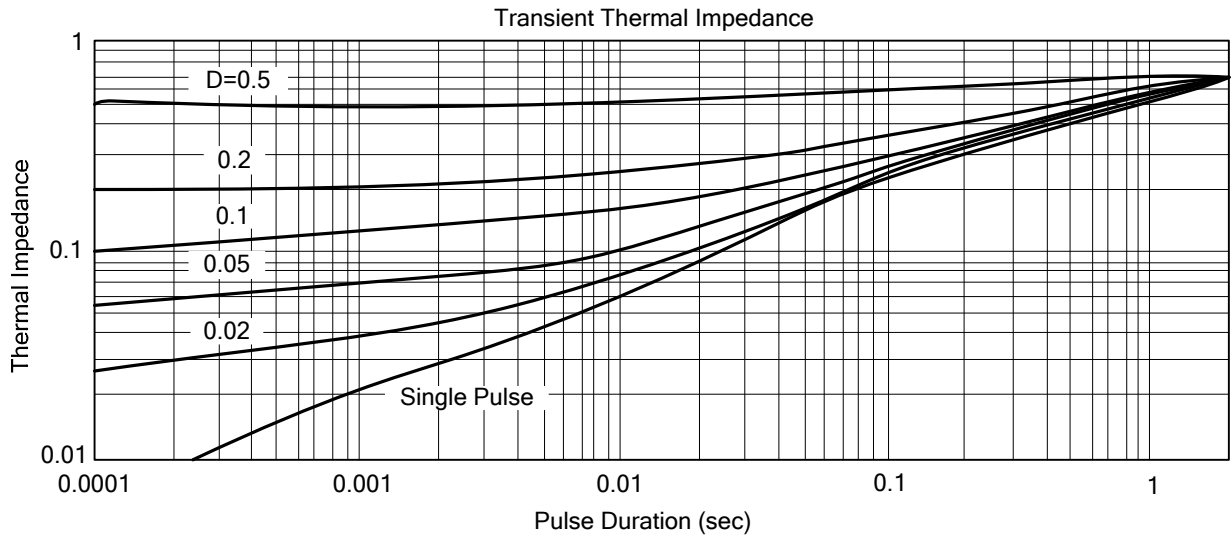
| PARAMETER  | SYMBOL       | TEST CONDITIONS  | MIN   | TYP  | MAX       | UNIT          |
|--|--------------|--|-------|------|-----------|---------------|
| <b>OFF CHARACTERISTICS</b>                             |              |  |       |      |           |               |
| Drain-Source Breakdown Voltage                         | $BV_{DSS}$   | $V_{GS}=0\text{V}, I_D=-250\mu\text{A}$  | -20   |      |           | V             |
| Drain-Source Leakage Current                           | $I_{DSS}$    | $V_{DS}=-16\text{V}, V_{GS}=0\text{V}$   |       |      | -1        | $\mu\text{A}$ |
| Gate-Source Leakage Current                            | $I_{GSS}$    | $V_{GS}=\pm 8\text{V}, V_{DS}=0\text{V}$   |       |      | $\pm 100$ | nA            |
| <b>ON CHARACTERISTICS</b>                              |              |  |       |      |           |               |
| Gate Threshold Voltage                                 | $V_{GS(TH)}$ | $V_{DS}=V_{GS}, I_D=-250\mu\text{A}$   | -0.45 |      |           | V             |
| Static Drain-Source On-State Resistance (Note 2)       | $R_{DS(ON)}$ | $V_{GS}=-4.5\text{V}, I_D=-2.8\text{A}$  |       | 95   | 130       | m $\Omega$    |
|  |              | $V_{GS}=-2.5\text{V}, I_D=-2.0\text{A}$  |       | 122  | 190       | m $\Omega$    |
| <b>DYNAMIC CHARACTERISTICS</b>                         |              |  |       |      |           |               |
| Input Capacitance                                      | $C_{ISS}$    | $V_{GS}=0\text{V}, V_{DS}=-6\text{V}, f=1.0\text{MHz}$                             |       | 447  |           | pF            |
| Output Capacitance                                     | $C_{OSS}$    |  |       | 127  |           | pF            |
| Reverse Transfer Capacitance                           | $C_{RSS}$    |  |       | 80   |           | pF            |
| <b>SWITCHING CHARACTERISTICS</b>                       |              |  |       |      |           |               |
| Turn-ON Delay Time (Note 2)                            | $t_{D(ON)}$  | $V_{DS}=-6\text{V}, V_{GS}=-4.5\text{V}, I_D=-1\text{A}, R_G=6\Omega, R_L=6\Omega$ |       | 5    | 25        | ns            |
| Turn-ON Rise Time                                      | $t_R$        |  |       | 19   | 60        | ns            |
| Turn-OFF Delay Time                                    | $t_{D(OFF)}$ |  |       | 95   | 110       | ns            |
| Turn-OFF Fall Time                                     | $t_F$        |  |       | 65   | 80        | ns            |
| Total Gate Charge (Note 2)                             | $Q_G$        | $V_{DS}=-6\text{V}, V_{GS}=-4.5\text{V}, I_D=-2.8\text{A}$                         |       | 5.4  | 10        | nC            |
| Gate-Source Charge                                     | $Q_{GS}$     |  |       | 0.8  |           | nC            |
| Gate-Drain Charge                                      | $Q_{GD}$     |  |       | 1.1  |           | nC            |
| <b>SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS</b> |              |  |       |      |           |               |
| Drain-Source Diode Forward Voltage (Note 2)            | $V_{SD}$     | $V_{GS}=0\text{V}, I_S=-1.6\text{A}$   |       | -0.8 | -1.2      | V             |
| Maximum Continuous Drain-Source Diode Forward Current  | $I_S$        |  |       |      | -1.6      | A             |

- Notes: 1. Pulse width limited by  $T_{J(MAX)}$   
 2. Pulse width  $\leq 300\mu\text{s}$ , duty cycle  $\leq 2\%$ .  
 3. Surface mounted on 1 in<sup>2</sup> copper pad of FR4 board

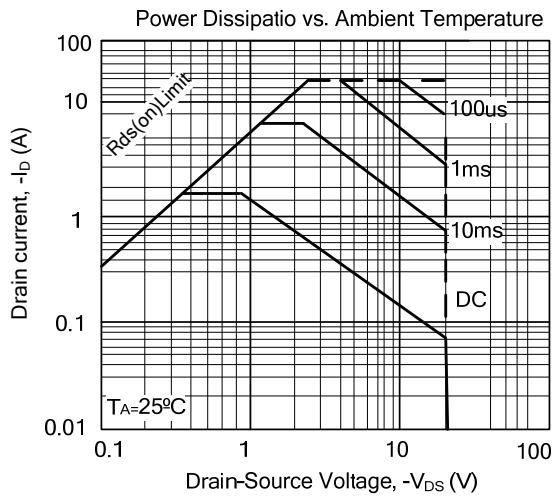
■ TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS(Cont.)



### ■ TYPICAL CHARACTERISTICS(Cont.)



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